Optical evidence of an enhanced electronic effective mass in the anomalous Pb$_{1-x}$Tl$_x$Te superconductor

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The narrow band-gap semiconductor PbTe exhibits a number of striking properties upon thallium (Tl)-doping, including the onset of superconductivity at temperatures $T_c$ which are substantially higher than for materials with equivalent charge carrier concentration. Here we provide a thorough optical investigation of Pb$_{1-x}$Tl$_x$Te over a very broad spectral range and contrast its normal-state, complete excitation spectrum with the optical response of the nonsuperconducting analog Na-doped PbTe. We capture the relevant energy scales shaping their electronic structure and uncover the formation of an impurity band upon doping with Tl, which evolves into a resonant state for large doping. This implies a large density of states and an enhancement of the optical effective mass $m^*/m_e$ of the itinerant charge carriers, which is stronger for Tl- than for Na-doping. Since the enhancement of $m^*/m_e$ particularly occurs upon crossing a critical concentration $x_c$ in Tl-doped PbTe for which $T_c \neq 0$, we advance its relevance for the onset of superconductivity.

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I. INTRODUCTION

The thermoelectric material PbTe, besides providing an alternative for power generation and refrigeration [1,2], also presents a series of unusual and poorly understood low-temperature electronic properties when appropriately doped. Of particular relevance to the present work, Tl substitution yields a metallic state, with no carrier freeze-out to the lowest temperatures, and a superconducting ground state for concentrations $x > x_c \sim 0.3\%$. The critical temperature increases linearly with the concentration of Tl dopants, with maximum values ($T_c \sim 1.4$ K [3]) that are anomalously high for the given carrier density of about $10^{20}$ holes/cm$^3$ [4,5]. Significantly, Tl is the only dopant to cause superconductivity in this material, so, for example, the analogous case of hole doping via Na substitution does not lead to superconductivity down to the lowest investigated temperature. It has therefore been conjectured that the special nature of the Tl impurities plays a prominent role [6–8].

The anomalous electronic properties of Pb$_{1-x}$Tl$_x$Te have previously been discussed in the context of the well-known valence-skipping nature of Tl, such that only Tl$^{1+}$ and Tl$^{3+}$ are the stable electronic configuration in ionic compounds. Such a mixed valency was indeed recently established spectroscopically [9]. The precise role played by such a mixed valence with respect to the superconductivity is presently unknown, but one possibility that has been suggested is that quantum valence fluctuations might set the stage for an electronic pairing mechanism [7,8].

Closely related to the observation of mixed valency, recent experimental work [10], based on a combination of magnetoresistance measurements (Shubnikov de Haas oscillations and Hall coefficient), angle-resolved photoemission spectroscopy (ARPES), and density functional theory (DFT) calculations of the electronic structure, found that for Tl concentrations beyond $x_c$, the Fermi energy ($\epsilon_F$) coincides with resonant impurity states. DFT calculations further indicate that these states derive principally from Tl orbitals [11,12], in which case the formal valence of the Tl impurities varies between 1+ and 3+ if the states are filled or empty. Such states should lead to a large density of states (DOS) and a strong enhancement of the average carrier effective mass. This observations motivate a more detailed investigation of the wider electronic structure by probing the charge dynamics; this is the purpose of the present work. Our results suggest that heavy charge carriers located at the Fermi level are a central component of the anomalous superconducting ground state found in this material.

II. EXPERIMENT

The Tl- and Na-doped PbTe single crystals were grown by an unseeded physical vapor transport method, by sealing in vacuum polycrystalline pieces of the already doped compound, with (or close to) the desired final stoichiometry [5,10,13]. The determination of the Tl and Na concentration was performed by comparing the measured Hall number of any given sample against a previously established calibration curve as well as by electron microprobe...
analysis. Table I summarizes the nominal doping content \(x\) and \(y\) for \(\text{Pb}_{1-x}\text{Ti}_{x}\text{Te}\) and \(\text{Pb}_{1-y}\text{Na}_{y}\text{Te}\), investigated in this study, along with their charge carrier concentrations \(p_{\text{Hall}}\) and Sommerfeld \(\gamma\) values from Hall and specific heat data, respectively [10,13]. Even though we do not provide data at exactly the very same doping content (for both Ti- and Na-doped PbTe), the investigated compositions cover the same range of charge carrier concentration after the Hall data.

We measure the temperature \((T)\) dependence of the optical reflectivity \(R(\omega)\) at nearly normal incidence with a Fourier-transform infrared interferometer (Bruker Vertex 80v), working in the spectral range from the far-infrared (FIR) up to the near-infrared (NIR), i.e., between 30 and 12 000 cm\(^{-1}\). This set of data is complemented at room temperature with those obtained by the PerkinElmer Lambda 950 from NIR up to the ultra-violet (UV) range, i.e., 4000–48 000 cm\(^{-1}\). For the purpose of the Kramers-Kronig (KK) transformation of \(R(\omega)\), to access the optical functions, we perform the following appropriate extrapolations at high frequencies as well as towards zero [14]: for \(\omega \rightarrow 0\), we made use of the Hagen-Rubens formula \(R(\omega) = 1 - \frac{2}{\sqrt{\pi}} \omega \), inserting the \(dc\) conductivity values \(\sigma_{dc}\) consistent with the relative \(T\) dependence of the transport data from Ref. [15], and above the upper frequency limit we consider the extrapolation \(R(\omega) \sim \omega^{-s} (2 < s < 4)\) to approach the electronic continuum [14].

### III. RESULTS AND DISCUSSION

Figures 1(a) and 1(b) display the measured reflectivity \(R(\omega)\) at 10 K of representative Ti- and Na-compositions, compared to the spectra of the pristine PbTe compound. The \(T\) evolution of \(R(\omega)\) is deployed for selected compounds in Fig. 4 in the Appendix A1. Some qualitative observations can be immediately made: the \(R(\omega)\) spectrum of PbTe attests to a rather poor conducting material, as evinced by the low frequency onset of an extremely over-damped plasma edge and due to Pb vacancies creating holes in the valence band. For the pristine compound, there is also a broad feature at about 180 cm\(^{-1}\) that overlaps with the weak, vacancies-induced plasma edge. It is caused by a so-called mixed plasmon-phonon mode [16,17].

![FIG. 1. (a), (b) \(R(\omega)\) and (c), (d) \(\sigma_1(\omega)\) at 10 K of representative Ti- and Na-doped PbTe compositions, respectively, compared to the spectra of the pristine PbTe compound. The insets in panels (c) and (d) display \(\sigma_1(\omega)\) at 10 K for the same compositions up to \(4 \times 10^8\) cm\(^{-1}\) (logarithmic energy scale). The vertical dashed lines in the insets mark the cutoff energy scales \(\omega_c \sim 100\) and 1000 cm\(^{-1}\) (see text).](image)

Doping PbTe by Na and Ti leads to a rather common evolution of the optical response with respect to the pristine compound, even though important nuances allow the differentiation of the absorption features of both investigated compositions. Upon doping we initially observe the formation of a rather sharp plasma edge in the measured \(R(\omega)\) quantity [Figs. 1(a) and 1(b) and Fig. 4 in the Appendix A1]. For low Na-content that edge is overlapped by a strong additional FIR absorption at about 300 cm\(^{-1}\). For low Ti-doping though, this latter feature is broader than for equivalent Na-compositions. The most remarkable change is observed at large doping, at which the plasma edge of \(R(\omega)\) move towards higher frequencies. Upon doping, \(R(\omega)\) also progressively gets overdamped, prior to a sharp increase of \(R(\omega)\) at the lowest frequencies accessible by our experiment. This latter behavior is more pronounced in Ti- than in Na-doped PbTe. This signals a stronger increase of the scattering in Ti-compositions than in Na-doped PbTe for the great majority of the doping-induced itinerant charge carriers. Conversely, a residual small fraction of the free charge carriers with long relaxation time seems to shape the charge dynamics at the lowest frequencies in both compositions. The FIR absorption feature at large doping is at most a broad shoulder overlapping with the plasma edge of \(R(\omega)\) for both Na- and Ti-doped PbTe.

The resulting real part \(\sigma_1(\omega)\) of the optical conductivity at 10 K is shown in Figs. 1(c) and 1(d) for selected compositions up to 2000 cm\(^{-1}\). \(\sigma_1(\omega)\) images the features recognized in \(R(\omega)\) as the Drude resonance and the FIR absorption and their evolution upon doping. As elaborated in Fig. 5 in the Appendix A1, there is a rather monotonic \(T\) dependence of those features for each doping, mostly coinciding with their overall enhancement at low \(T\). The charge dynamics for all compounds is dominated by the strong absorption peaked at
about $\omega_0 \sim 10^2 \text{ cm}^{-1}$ and with a low frequency onset around 2000 cm$^{-1}$ [insets of Figs. 1(c) and 1(d)]. This feature is in broad agreement with previous optical investigations (see Ref. [18] for an ample literature), focusing the attention to the high frequency visible and UV spectral ranges and addressing the narrow-gap excitation, which can be well reproduced by first principle calculations [18]. The low frequency spectral range displays the metallic (but weak) Drude resonance, which is ascribed to the so-called coherent contribution of $\sigma_1(\omega)$. It generally appears upon doping and tends to further extend into a broad tail at higher frequencies, labeled as the incoherent component of $\sigma_1(\omega)$. For the TI-doped PbTe at $x > x_c$, the coherent metallic term develops at rather low frequencies. The FIR mode shifts to higher frequencies with doping at all PbTe compositions and is overlapped to the incoherent metallic part of $\sigma_1(\omega)$. This latter absorption is quite sharp for low Na-doping while it broadens upon increasing the doping concentration [Fig. 1(c)]. At variance for all TI-compositions the FIR feature distributes over a broad energy interval in $\sigma_1(\omega)$ [Fig. 1(d)], as already pointed out above when describing the $R(\omega)$ spectra.

The impact of doping has been extensively studied both experimentally and theoretically, showing diverse effects as a function of dopant into the physical properties [19–21]. It is generally recognized that the resulting optical response features so-called impurity energy states, which give rise to electronic interband transitions located in the FIR spectral range just above the metallic Drude resonance [19]. We may already anticipate the common notion [19–21] that a pinning of $\epsilon_F$ to the impurity state occurs upon increasing the dopant concentration, although it depends from the dopant itself and its degree of hybridization with the valence band. The broadening of the FIR absorption feature with increased doping content suggests that the impurity energy states are somewhat broadly distributed in energy.

We now turn our attention to the tools for the data analysis, with the main goal to extract from $\sigma_1(\omega)$ the concentration ($n$) and the effective mass ($m^*/m_e$) of the itinerant charge carriers. First of all, we introduce the well-established instrument of the integrated spectral weight, which is defined as the integral of $\sigma_1(\omega)$ up to a cutoff energy ($\omega_c$):

$$SW(T; \omega_c) = \int_0^{\omega_c} \sigma_1(\omega, T)d\omega.$$  (1)

This model-independent quantity conveys the number of the carriers, normalized by their effective mass, contributing to the optical processes up to $\omega_c$. Therefore, in the $\omega_c \to \infty$ limit, it is expected to merge into a constant value at all $T$, satisfying the $f$-sum rule [14]. In our data, the full recovery of $SW$ is achieved at energy scales of about 2 eV ($1.6 \times 10^4 \text{ cm}^{-1}$) for all compositions, well within the measurable spectral range and thus excluding reshuffling of $SW$ among energy scales outside our experimental energy interval. Figure 2 displays the corresponding evolution of $SW$ normalized by its value at 300 K as a function of $T$ and doping content for different cut-off frequencies $\omega_c$ (for additional details we refer to Fig. 6 in the Appendix A2). We point out the astonishing accumulation of $SW$, to be addressed later, with respect to 300 K at FIR frequencies (i.e., $\omega_c \sim 100$–500 cm$^{-1}$), principally occurring below $T^* \sim 100$ K and for TI-compositions with $x \sim x_c$. For the purpose of our analysis we will exclusively consider the cutoff frequencies at 100 and 1000 cm$^{-1}$ [see vertical marks in the insets of Figs. 1(c) and 1(d)]. The first one identifies the range where the coherent part of $\sigma_1(\omega)$ (i.e., Drude resonance) expires, while the second one is at the end of the incoherent part of $\sigma_1(\omega)$ right at the onset of the narrow-gap absorption [18].

To obtain both $m^*/m_e$ and $n$, we must consider an additional constraint, given by the Sommerfeld $\gamma$ value of the electronic specific heat, which necessarily encompasses all states at $\epsilon_F$. From its definition we can evince the following expressions [22,23] ($\omega_p = 2\pi v_p$):

$$\frac{m^*}{m_e} = \left(\frac{\gamma}{V_m}\right)^{3/4} \frac{1}{\sqrt{2\pi} v_p}, \quad n = \left(\frac{\gamma}{V_m}\right)^{3/4} (2\pi v_p)^{3/2},$$  (2)

where $V_m$ is the molar volume [24]. Both expressions obviously imply that $\gamma \sim (3\pi^2 n)^{1/3} V_m$. The integrated $SW(\omega_c)$ of Eq. (1) can be understood as an oscillator strength, which would be proportional to the squared plasma frequency $\omega_p^2 = \frac{4\pi\epsilon_0 \omega_c}{m_e}$ of the metallic-like, coherent (Drude) contribution when

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FIG. 2. $T$ and doping content dependence of the integrated spectral weight $SW$ [Eq. (1)] from zero up to the indicated cutoff frequency $\omega_c$, normalized by its value at 300 K, for both PbTe compositions. A first-neighbor interpolation procedure is used to generate the color maps.

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The effective mass for Tl-doped PbTe is more strongly enhanced in Tl-doped PbTe compositions for a Tl1 dopant were to contribute a single hole (as expected for a Tl\textsuperscript{1+} valence), but still gives a significantly higher estimate of the carrier concentration than the L-pocket Luttinger volume, for composition exceeding $\chi_c$ [10]. It is natural to conclude that in Tl-doped PbTe there must be additional mobile states outside of the L-pocket, located within a relatively narrow band at $\epsilon_F$ and resonating with the L-pocket itself. This immediately leads to DOS in the inset of Fig. 3(a), as first proposed by Ref. [10].

The formation of the resonant band at $\epsilon_F$ might be very much associated with the valence skipper property of the Tl ion and its origin could be related to the scenario based on the charge Kondo model [7], as originally advanced by dc transport data [5]. However, since the impurity levels are somewhat broadened in energy, the best picture to have in mind is that of virtual bound states. In such a picture, the width of the resonant states, having predominantly Tl character, is controlled first by the hybridization with the PbTe bands (mostly L band), and second by the overlap with nearby impurity states. $\epsilon_F$ lies close or within the resonant impurity band, which is centered below the top of the valence band and can contribute to the conductivity.

Our findings corroborate these later notions. Although $\sigma_1(\omega)$ in both PbTe compositions may be commonly addressed within the proposed DOS (inset of Fig. 3(a) [10]), its consequences for the optical response are more pertinent for the Tl-doped PbTe. First of all, the resulting metallic $\sigma_1(\omega)$ after the sketched DOS will encounter a coherent as well as incoherent component which tend to be distinct upon increasing the doping content. One could state that in doped PbTe the itinerant carriers are somehow localized on the short and delocalized on the long wave length limit. The fraction of carriers located within the DOS resonance pinned at $\epsilon_F$ are characterized by a large effective mass, which turns out to be strongly enhanced in Tl-doped PbTe compositions for $x > \chi_c$ rather than in Pb$_{1-x}$Na$_x$Te [Figs. 3(a) and 3(b)]. The second generic optical feature is the FIR absorption originating from the impurity states, which is quite sharp at low doping content. This excitation then transforms into a broader absorption, located at higher energies upon increasing the doping concentration, when the hybridization of the impurity

\begin{align*}
\omega_c &= 100 \text{ cm}^{-1} \quad \text{or of the total coherent and incoherent components in } \sigma_1(\omega) \text{ when } \omega_c = 1000 \text{ cm}^{-1} [25]. \text{ We can then plug into Eq. (2) the integrated spectral weight } SW(\omega_c) \text{ for } \omega_c, \\
\text{and together with the measured Sommerfeld } \gamma \text{ values (Table I).} \\
\text{Figure 3 summarizes the outcome of this analysis, showing the } m^*/m_e \text{ and } n \text{ as a function of the doping content. The effective mass for Tl-doped PbTe is more strongly enhanced upon crossing } \chi_c \text{ than for any Na-doped compositions. This is particularly emphasized for the estimation of } m^*/m_e \text{ at } \omega_c = 100 \text{ cm}^{-1} \text{ which possibly represents the true mass enhancement of the itinerant carriers located in the (coherent) Drude-like resonance.} \text{ In the Appendix B we elaborate further on the relationship between } m^*/m_e \text{ and } n \text{ from the representation } m^* \sim n^{-1/3} \text{, as expected from Eq. (2), and by imposing } n = p_{\text{Hall}} \text{ we can also confirm that } m^*_{\text{Tl}}>m^*_{\text{Na}} \text{ for increasing doping content (Fig. 7).} \\
\text{This later representation of our data analysis emphasises the robustness of the mass enhancement for the Tl compositions with equivalent } p_{\text{Hall}} \text{ than the Na-ones. While the definition of the effective mass depends very much from the performed experiment [26], we note a fair agreement as far as the overall trend is concerned between our optical effective mass [Figs. 3(a) and 3(b)] and the cyclotron mass determined from the Shubnikov de Haas oscillations’ amplitude (Fig. S7 in the Supplemental Material of Ref. [10]).} \\
The extracted charge carrier concentration } n \text{ up to } \omega_c \sim 100 \text{ cm}^{-1} \text{ for both PbTe compositions is quite small, particularly for large doping content (i.e., exceeding } \chi_c \text{ for Tl-doped PbTe), with respect to the measured } p_{\text{Hall}}, \text{ which is also shown as comparison in Figs. 3(c) and 3(d). This means that just a fraction of the charge carrier concentration, introduced by doping, is encountered in the coherent component (i.e., effective Drude-like resonance) of } \sigma_1(\omega). \text{ In this respect and interestingly enough, our estimation of } n \text{ after Eq. (2) does coincide fairly well with } p_{\text{Hall}}, \text{ when } \sigma_1(\omega) \text{ is integrated up to } \omega_c \sim 1000 \text{ cm}^{-1}. \text{ This anticipates the idea (see below) that the conduction band in Tl- as well as Na-doped PbTe results from hole-doping of the valence band [most probably at the L-point of the Brillouin zone (BZ)] and that a great portion of the charge carriers contributes to the incoherent component of } \sigma_1(\omega). \\
\end{align*}
level with the valence band takes place. That broad absorption at 1000 cm\(^{-1}\), which overlaps the incoherent contribution to \(\sigma_1(\omega)\), basically stems from excitations between the states with (mainly) \(\Sigma\)-band character and the impurity band pinned at \(\epsilon_F\). In fact, the relative difference between the top of the \(L\) and \(\Sigma\) band ranges between 130 and 200 meV in PbTe, as revealed in ARPES \([10,27]\). With doping this energy scale should get smaller, thus being comparable to and consistent with the frequency range of our (broad) FIR absorption.

Even though we focus here our attention on the data at 10 K, it is worthwhile to briefly comment on the \(T\) dependence of the optical response. This is particularly subtle in terms of the relative \(SW\) reshuffling with respect to 300 K (Fig. 2). Interestingly enough our characteristic temperature \(T^*\) coincides with \(T_K \sim 50–70\) K extracted from thermoelectric power (TEP) \([28]\) in \(Pb_{1-x}Tl_xTe\) \((0 \leq x \leq 1.3\%\)) after concepts based on the physics of dilute magnetic alloys. To which extent such a Kondo-like physics (e.g., charge-Kondo scenario \([7,8]\)) is pertinent to the title compound is beyond the scope of our work and it is generally highly debated. Already the variation by almost a factor of 10 in the estimation of \(T_K\) between transport properties \((T_K \sim 5\) K) \([5]\) and TEP \([28]\) is indicative of the limitations of such a scenario. Here, we wish to highlight the necessity to reach low enough \(T\) (i.e., \(< T^*\) for \(x \sim x_c\)), so that the thermal broadening \(k_BT\) is smaller than the width \((\Gamma)\) of the resonant band pinned at \(\epsilon_F\), a prerequisite to resolve it. Therefore, we propose \(\Gamma \sim k_BT^*\) as the relevant energy scale in Tl-doped PbTe at least for \(x \sim x_c\). Upon increasing \(x\) beyond \(x_c\), \(\Gamma\) is already substantially larger than the thermal broadening at 300 K, so that upon lowering \(T\) the relative change of \(SW\) with respect to 300 K is less pronounced and tends then to disappear.

IV. CONCLUSION

Even though the overall optical response for both Na- and Tl-doped PbTe shares rather common, similar features, it clearly emerges from our investigation, that the effective optical mass \(m^*/m_e\) is the key quantity somehow discriminating between the two investigated PbTe compositions. We provide evidence for a strong enhancement of the optical effective mass in \(Pb_{1-x}Tl_xTe\) for \(x > x_c\) than in \(Pb_{1-y}Na_yTe\). Our results advance, in principle, the intriguing possibility that superconductivity may be the consequence of the pairing of “heavy” quasiparticles associated to charged valence states \([9]\).

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APPENDIX A: ADDITIONAL DATA AND ANALYSIS

1. Optical reflectivity and conductivity

Complementary to the data reported in the main paper, we review here in Fig. 4 the \(T\) dependence of the measured \(R(\omega)\) up to 2000 cm\(^{-1}\) for representative compositions of Tl- and Na-doped PbTe. The spectra at high frequencies for both compositions do coincide with \(R(\omega)\) of PbTe, shown in the inset at 10 K and in the whole spectral range. This also means that we could apply above 48 000 cm\(^{-1}\) the same extrapolation procedure at all compositions for the KK transformation. This strengthens the reliability of our \(R(\omega)\) data and extracted \(\sigma_1(\omega)\) below 5000 cm\(^{-1}\), where the main discussion is developed and the major conclusions of our work emerge.

Even a small concentration of Pb or Te vacancies in PbTe leads to metallic behavior. In our case, due to the synthesis conditions/methods that we employ, it is Pb vacancies. The large dielectric constant of PbTe screens the resulting impurity potential very effectively, and the holes do not freeze-out to the lowest \(T\) (i.e., they form a Fermi surface).

We can reiterate and emphasise the progressively enhanced optical metallicity [i.e., the appearance of the plasma edge in \(R(\omega)\)] upon doping. The onset of the plasma edge gets sharper (particularly at low doping concentrations for both PbTe compositions) and the edge itself tends to undergo a blue-shift upon lowering \(T\). Once again, we wish to note the more strongly overdamped behavior of \(R(\omega)\) at all \(T\) for high
TI-doping. The metallic behavior of \( R(\omega) \) results in a Drude component of the real part \( \sigma_1(\omega) \) of the optical conductivity (Fig. 5), which becomes narrower upon lowering \( T \) at any doping concentration \( x \) or \( y \). As anticipated in the main paper, we recall again that at large doping the so-called incoherent component of \( \sigma_1(\omega) \) tends to dominate over the small coherent part developing at low frequencies. We also observe a FIR absorption at about 300 cm\(^{-1}\), which is narrower at low doping content for the Na-doped than for Tl-doped PbTe (insets of Fig. 5). Upon increasing the doping content such a feature gets broader in Na-doped PbTe compounds and shifts to higher frequencies for both PbTe compositions. That FIR absorption is enhanced upon lowering \( T \) in Na- and Tl-doped PbTe.

2. Spectral weight reshuffling

The integrated spectral weight \( SW \), defined in Eq. (1), is a key quantity in our proposed data analysis. Here, we further elaborate on its distribution and reshuffling as a function of \( T \) and doping content. In addition to Fig. 2, one can consider the spectral weight normalized to 300 K encountered in \( \sigma_1(\omega) \) between 100 and 1000 cm\(^{-1}\) [vertical dashed lines in the insets of Figs. 1(c) and 1(d)], as shown in Fig. 6. This quantity \( (SW)_{100-1000} \) is related to the energy interval of the high frequency Drude tail and incoherent (metallic) contribution as well as the impurity mode. Also from this perspective, one can evince a stronger enhancement of \( SW_{100-1000} \) with respect to 300 K for Tl-doped PbTe at doping content around \( x_c \) than for any Na-doped PbTe, which

FIG. 5. Real part \( \sigma_1(\omega) \) of the optical conductivity of representative Na- (upper row) and Tl-doped PbTe (lower row) at selected \( T \). The insets emphasise the \( T \) dependence of the FIR absorption feature (see main paper).

FIG. 6. \( T \) and doping content dependence of the integrated spectral weight \( (SW)_{100-1000} \) after Eq. (1) between 100 and 1000 cm\(^{-1}\) [vertical dashed lines in the insets of Figs. 1(c) and 1(d)], normalized by the same quantity at 300 K, for both PbTe compositions. A first-neighbor interpolation procedure is used to generate the color maps.
Figure 7 displays the effective mass \( m^*/m_e \) versus the charge carrier concentration \( n \) as estimated from Eq. (2) when inserting for \( \omega_p^2 \) the integrated spectral weight [Eq. (1)] up to selected \( \omega_c \) (see figure caption) for both sets of Tl- and Na-doped PbTe compositions at 10 K. As implicit in Eq. (2) themselves, all entries satisfy the relationship \( m^*/m_e \sim n^{-1/3} \). The purpose of this representation is to iterate that in Tl-doped PbTe the enhancement of the optical effective mass upon increasing \( n \) is more substantial than in any Na-doped compositions. For instance, one can observe how \( m^*/m_e \) behaves as a function of doping when taking \( n = p_{\text{Hall}} \). At such \( p_{\text{Hall}} \) values (vertical thin dashed lines in Fig. 7) the enhancement of \( m^*/m_e \) is in fact more pronounced in Tl- than in Na-doped PbTe.

**APPENDIX B: ALTERNATIVE VIEW ON THE OPTICAL EFFECTIVE MASS VERSUS CHARGE CARRIER CONCENTRATION**

It is worth mentioning that a new phonon mode appears in pure PbTe with increasing \( T > 100 \text{ K} \), which is accompanied by a giant anharmonic phonon scattering [29,30]. This implies a reshuffling of \( SW \), which, however, gets enhanced well above room temperature. Such a reshuffling involving phonon modes is generally expected to be rather tiny and moreover in this case it is obviously opposite as a function of \( T \) than in our findings. These arguments indicate that this cannot be the most relevant mechanism for the \( SW \) redistribution observed in our spectra (Figs. 2 and 6).


[24] The molar volume of PbTe is equal to \(40.48 \times 10^{-6} \text{ m}^3/\text{mole}\) and it has been considered equivalent for both Na- and Tl-PbTe compositions.

[25] The integration of \(\sigma_1(\omega)\) up to 1000 cm\(^{-1}\) encounters a fraction of \(SW\) due to the excitation originating from the impurity energy state. Nonetheless, we adopt here a \(SW\) analysis, which neglects an \textit{ad hoc} subtraction from the total \(SW\) of that contribution. This latter simplification may lead to an underestimation of \(m^*/m_e\) and an overestimation of \(n\), particularly at low Na-doping content, for which the FIR absorption is narrow and strong. Nevertheless, we are convinced that the overall conclusions of our work across several doping contents are not severely affected by our simplified \(SW\) procedure.


